Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	6488	semiconductor and (gate adj electrode) and (silicide) and (implant$ same silicon)	USPAT	ADJ	ON	2005/06/22 13:46
L2	586	semiconductor and (gate adj electrode) and ((silicide) same (implant$ near4 silicon))	USPAT	ADJ	ON	2005/06/22 14:06
L3	128	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	USPAT	ADJ	ON	2005/06/22 14:50
L4	53	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	US-PGPUB	ADJ	ON	2005/06/22 14:50
L5	0	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	IBM_TDB	ADJ	ON	2005/06/22 14:50
L6	9	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	DERWENT	ADJ	ON	2005/06/22 14:54
L7	0	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	EPO	ADJ	ON	2005/06/22 14:54
L8	26	semiconductor and (gate adj electrode) and ((silicide) same (implant$ adj silicon))	JPO	ADJ	ON	2005/06/22 14:54